

16-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCES014E – JULY 1995 – REVISED FEBRUARY 1999

- **Member of the Texas Instruments Widebus™ Family**
- **EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors**
- **Package Options Include Plastic 300-mil Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), and Thin Very Small-Outline (DGV) Packages**

description

This 16-bit buffer/driver is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74ALVCH16244 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. It provides true outputs and symmetrical active-low output-enable (\overline{OE}) inputs.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74ALVCH16244 is characterized for operation from -40°C to 85°C .

DGG, DGV, OR DL PACKAGE (TOP VIEW)

| | | | |
|------------------|----|----|------------------|
| $\overline{1OE}$ | 1 | 48 | $\overline{2OE}$ |
| 1Y1 | 2 | 47 | 1A1 |
| 1Y2 | 3 | 46 | 1A2 |
| GND | 4 | 45 | GND |
| 1Y3 | 5 | 44 | 1A3 |
| 1Y4 | 6 | 43 | 1A4 |
| V_{CC} | 7 | 42 | V_{CC} |
| 2Y1 | 8 | 41 | 2A1 |
| 2Y2 | 9 | 40 | 2A2 |
| GND | 10 | 39 | GND |
| 2Y3 | 11 | 38 | 2A3 |
| 2Y4 | 12 | 37 | 2A4 |
| 3Y1 | 13 | 36 | 3A1 |
| 3Y2 | 14 | 35 | 3A2 |
| GND | 15 | 34 | GND |
| 3Y3 | 16 | 33 | 3A3 |
| 3Y4 | 17 | 32 | 3A4 |
| V_{CC} | 18 | 31 | V_{CC} |
| 4Y1 | 19 | 30 | 4A1 |
| 4Y2 | 20 | 29 | 4A2 |
| GND | 21 | 28 | GND |
| 4Y3 | 22 | 27 | 4A3 |
| 4Y4 | 23 | 26 | 4A4 |
| $\overline{4OE}$ | 24 | 25 | $\overline{3OE}$ |

FUNCTION TABLE
(each 4-bit buffer)

| INPUTS | | OUTPUT |
|-----------------|---|--------|
| \overline{OE} | A | Y |
| L | H | H |
| L | L | L |
| H | X | Z |

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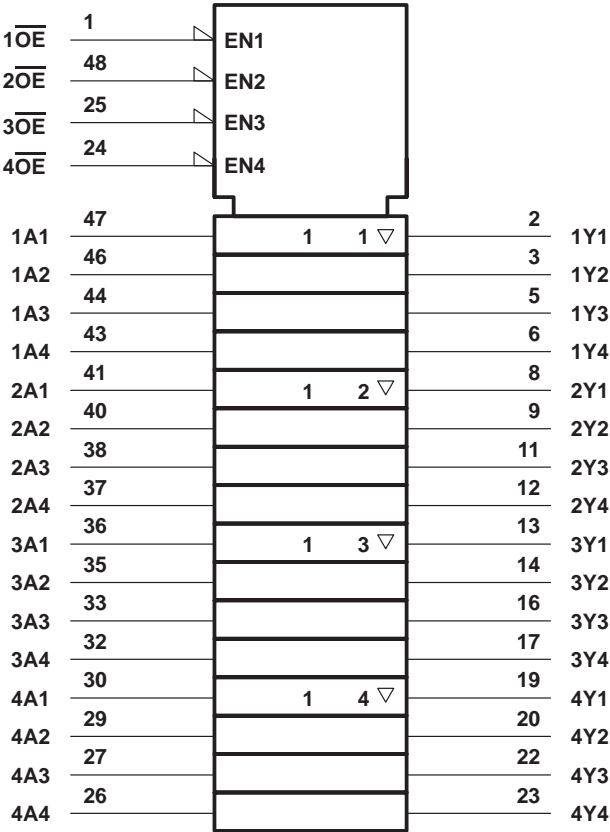
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SN74ALVCH16244
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logic symbol†



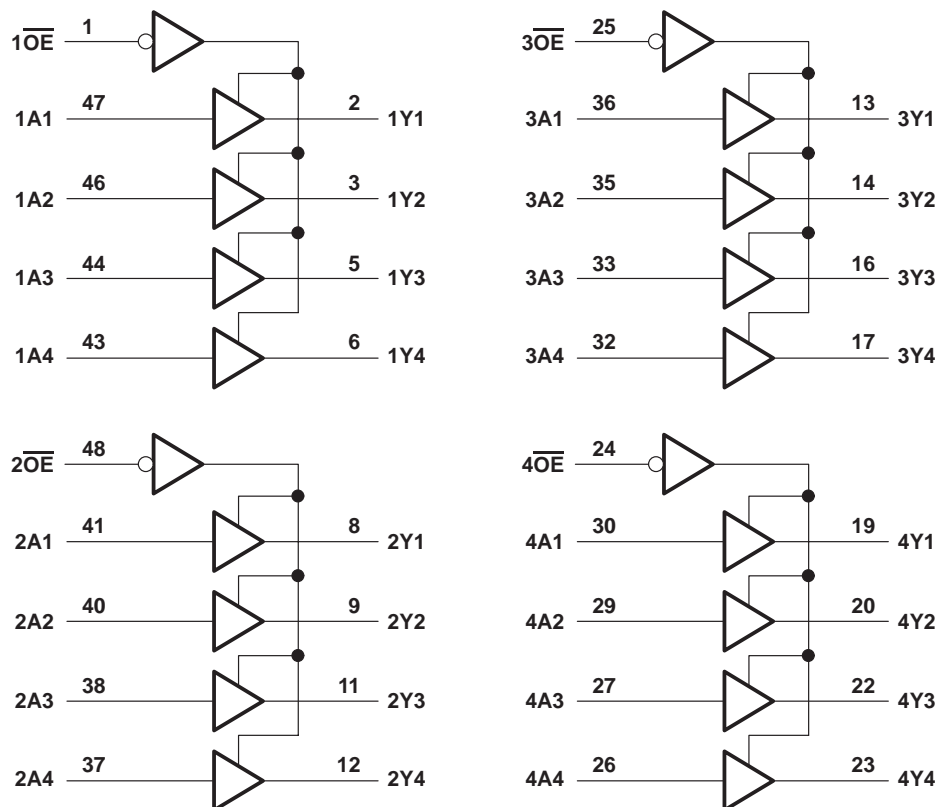
† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

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logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

| | |
|--|----------------------------|
| Supply voltage range, V_{CC} | –0.5 V to 4.6 V |
| Input voltage range, V_I (see Note 1) | –0.5 V to 4.6 V |
| Output voltage range, V_O (see Notes 1 and 2) | –0.5 V to $V_{CC} + 0.5$ V |
| Input clamp current, I_{IK} ($V_I < 0$) | –50 mA |
| Output clamp current, I_{OK} ($V_O < 0$) | –50 mA |
| Continuous output current, I_O | ±50 mA |
| Continuous current through each V_{CC} or GND | ±100 mA |
| Package thermal impedance, θ_{JA} (see Note 3): DGG package | 89°C/W |
| DGV package | 93°C/W |
| DL package | 94°C/W |
| Storage temperature range, T_{stg} | –65°C to 150°C |

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
 2. This value is limited to 4.6 V maximum.
 3. The package thermal impedance is calculated in accordance with JESD 51.

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recommended operating conditions (see Note 4)

| | | MIN | MAX | UNIT |
|---------------------|------------------------------------|---|----------------------|------|
| V_{CC} | Supply voltage | 1.65 | 3.6 | V |
| V_{IH} | High-level input voltage | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$ | $0.65 \times V_{CC}$ | V |
| | | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$ | 1.7 | |
| | | $V_{CC} = 2.7\text{ V to }3.6\text{ V}$ | 2 | |
| V_{IL} | Low-level input voltage | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$ | $0.35 \times V_{CC}$ | V |
| | | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$ | 0.7 | |
| | | $V_{CC} = 2.7\text{ V to }3.6\text{ V}$ | 0.8 | |
| V_I | Input voltage | 0 | V_{CC} | V |
| V_O | Output voltage | 0 | V_{CC} | V |
| I_{OH} | High-level output current | $V_{CC} = 1.65\text{ V}$ | –4 | mA |
| | | $V_{CC} = 2.3\text{ V}$ | –12 | |
| | | $V_{CC} = 2.7\text{ V}$ | –12 | |
| | | $V_{CC} = 3\text{ V}$ | –24 | |
| I_{OL} | Low-level output current | $V_{CC} = 1.65\text{ V}$ | 4 | mA |
| | | $V_{CC} = 2.3\text{ V}$ | 12 | |
| | | $V_{CC} = 2.7\text{ V}$ | 12 | |
| | | $V_{CC} = 3\text{ V}$ | 24 | |
| $\Delta t/\Delta v$ | Input transition rise or fall rate | | 10 | ns/V |
| T_A | Operating free-air temperature | –40 | 85 | °C |

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | V _{CC} | MIN | TYP† | MAX | UNIT |
|-----------------------|----------------|--|-----------------|----------------------|------|------|------|
| V _{OH} | | I _{OH} = –100 µA | 1.65 V to 3.6 V | V _{CC} –0.2 | | | V |
| | | I _{OH} = –4 mA | 1.65 V | 1.2 | | | |
| | | I _{OH} = –6 mA | 2.3 V | 2 | | | |
| | | I _{OH} = –12 mA | 2.3 V | 1.7 | | | |
| | | | 2.7 V | 2.2 | | | |
| | | | 3 V | 2.4 | | | |
| | | I _{OH} = –24 mA | 3 V | 2 | | | |
| V _{OL} | | I _{OL} = 100 µA | 1.65 V to 3.6 V | | | 0.2 | V |
| | | I _{OL} = 4 mA | 1.65 V | | | 0.45 | |
| | | I _{OL} = 6 mA | 2.3 V | | | 0.4 | |
| | | I _{OL} = 12 mA | 2.3 V | | | 0.7 | |
| | | | 2.7 V | | | 0.4 | |
| | | I _{OL} = 24 mA | 3 V | | | 0.55 | |
| I _I | | V _I = V _{CC} or GND | 3.6 V | | | ±5 | µA |
| I _I (hold) | | V _I = 0.58 V | 1.65 V | 25 | | | µA |
| | | V _I = 1.07 V | 1.65 V | –25 | | | |
| | | V _I = 0.7 V | 2.3 V | 45 | | | |
| | | V _I = 1.7 V | 2.3 V | –45 | | | |
| | | V _I = 0.8 V | 3 V | 75 | | | |
| | | V _I = 2 V | 3 V | –75 | | | |
| | | V _I = 0 to 3.6 V‡ | 3.6 V | | | ±500 | |
| I _{OZ} | | V _O = V _{CC} or GND | 3.6 V | | | ±10 | µA |
| I _{CC} | | V _I = V _{CC} or GND, I _O = 0 | 3.6 V | | | 40 | µA |
| ΔI _{CC} | | One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND | 3 V to 3.6 V | | | 750 | µA |
| C _i | Control inputs | V _I = V _{CC} or GND | 3.3 V | 3 | | | pF |
| | Data inputs | | | 6 | | | |
| C _O | Outputs | V _O = V _{CC} or GND | 3.3 V | 7 | | | pF |

† All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

‡ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

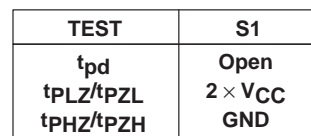
| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} = 1.8 V | V _{CC} = 2.5 V ± 0.2 V | | V _{CC} = 2.7 V | | V _{CC} = 3.3 V ± 0.3 V | | UNIT |
|------------------|------------------------|-------------|-------------------------|------------------------------------|-----|-------------------------|-----|------------------------------------|-----|------|
| | | | TYP | MIN | MAX | MIN | MAX | MIN | MAX | |
| t _{pd} | A | Y | § | 1 | 3.7 | 3.6 | | 1 | 3 | ns |
| t _{en} | $\overline{\text{OE}}$ | Y | § | 1 | 5.7 | 5.4 | | 1 | 4.4 | ns |
| t _{dis} | $\overline{\text{OE}}$ | Y | § | 1 | 5.2 | 4.6 | | 1 | 4.1 | ns |

§ This information was not available at the time of publication.

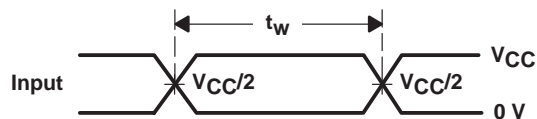
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| PARAMETER | | | TEST CONDITIONS | V _{CC} = 1.8 V | V _{CC} = 2.5 V | V _{CC} = 3.3 V | UNIT |
|-----------------|-------------------------------|------------------|------------------------------------|-------------------------|-------------------------|-------------------------|------|
| | | | | TYP | TYP | TYP | |
| C _{pd} | Power dissipation capacitance | Outputs enabled | C _L = 50 pF, f = 10 MHz | † | 16 | 19 | pF |
| | | Outputs disabled | | † | 4 | 5 | |

† This information was not available at the time of publication.

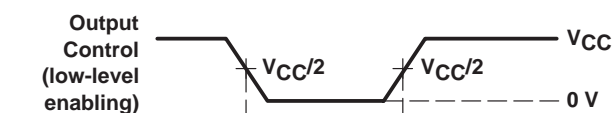


LOAD CIRCUIT

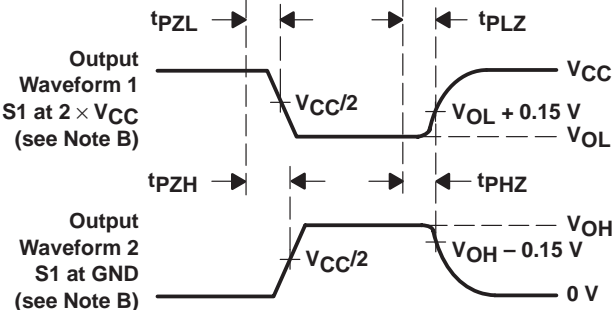


VOLTAGE WAVEFORMS

PULSE DURATION



VOLTAGE WAVEFORMS SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS PROPAGATION DELAY TIMES

VOLTAGE WAVEFORMS ENABLE AND DISABLE TIMES

- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10$ MHz, $Z_O = 50 \Omega$, $t_r \leq 2$ ns, $t_f \leq 2$ ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms

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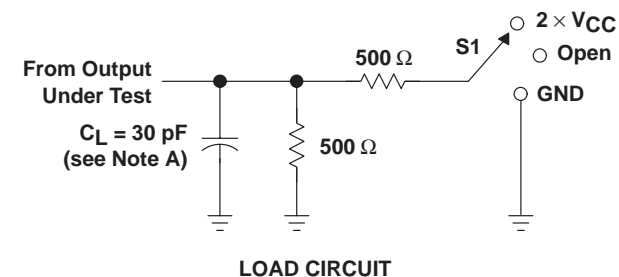
16-BIT BUFFER/DRIVER

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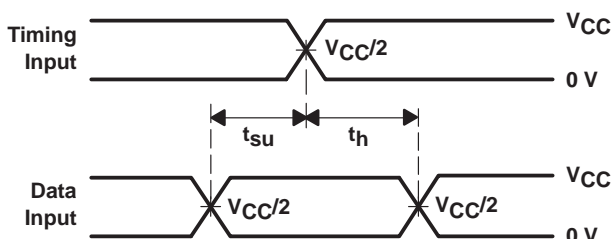
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PARAMETER MEASUREMENT INFORMATION

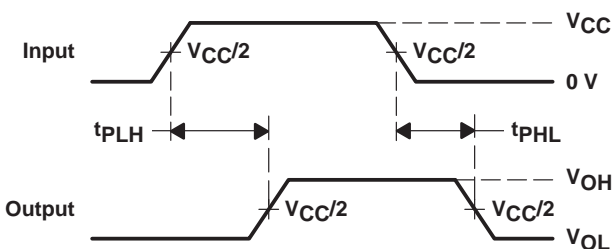
$$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$$



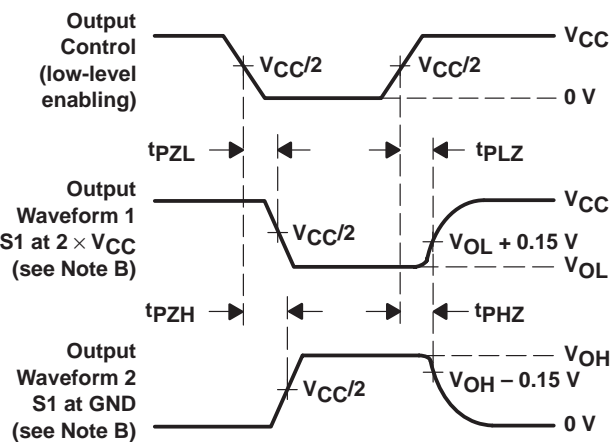
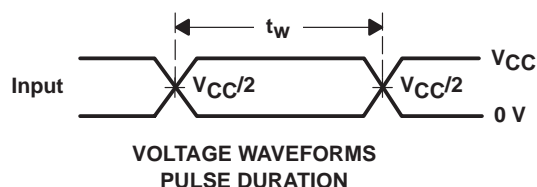
| TEST | S1 |
|-------------------|-------------------|
| t_{pd} | Open |
| t_{PLZ}/t_{PZL} | 2 $\times V_{CC}$ |
| t_{PHZ}/t_{PHL} | GND |



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

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 - All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2 \text{ ns}$, $t_f \leq 2 \text{ ns}$.
 - The outputs are measured one at a time with one transition per measurement.
 - t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - t_{PZL} and t_{PZH} are the same as t_{en} .
 - t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 2. Load Circuit and Voltage Waveforms

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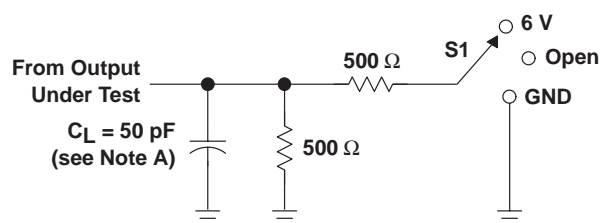
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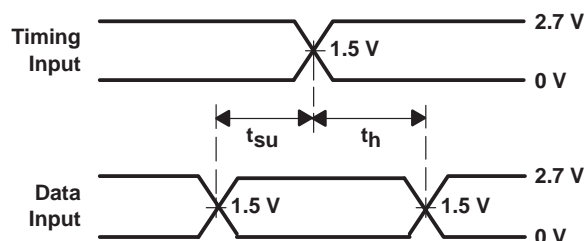
PARAMETER MEASUREMENT INFORMATION

$V_{CC} = 2.7 \text{ V AND } 3.3 \text{ V} \pm 0.3 \text{ V}$

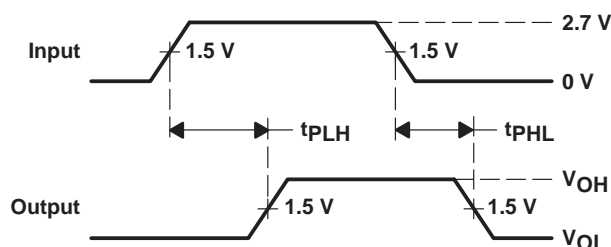


LOAD CIRCUIT

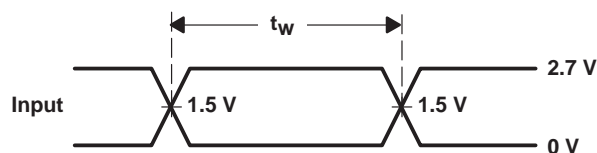
| TEST | S1 |
|-------------------|------|
| t_{pd} | Open |
| t_{PLZ}/t_{PZL} | 6 V |
| t_{PHZ}/t_{PZH} | GND |



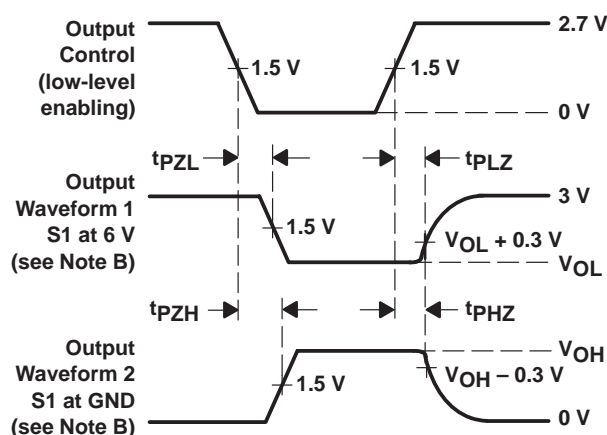
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

- NOTES:
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 - All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
 - The outputs are measured one at a time with one transition per measurement.
 - t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - t_{PZL} and t_{PZH} are the same as t_{en} .
 - t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 3. Load Circuit and Voltage Waveforms

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